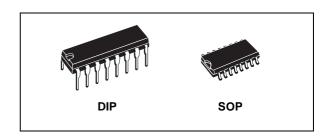


# **HCF4051B**

# SINGLE 8-CHANNEL ANALOG MULTIPLEXER

- LOW "ON" RESISTANCE : 125Ω (Typ.) OVER 15V p.p SIGNAL-INPUT RANGE FOR V<sub>DD</sub> - V<sub>EE</sub> = 15V
- HIGH "OFF" RESISTANCE : CHANNEL LEAKAGE ± 100pA (Typ.) at V<sub>DD</sub> V<sub>EE</sub> = 18V
- BINARY ADDRESS DECODING ON CHIP
- HIGH DEGREE OF LINEARITY : < 0.5% DISTORTION TYP. at  $f_{IS}$  = 1KHz,  $V_{IS}$  = 5  $V_{pp}$ ,  $V_{DD}$   $V_{SS}$  ≥ 10V, RL = 10K $\Omega$
- VERY LOW QUIESCENT POWER DISSIPATION UNDER ALL DIGITAL CONTROL INPUT AND SUPPLY CONDITIONS: 0.2 µW (Typ.) at V<sub>DD</sub> V<sub>SS</sub> = V<sub>DD</sub> V<sub>EE</sub> =10V
- $\begin{tabular}{ll} \hline & MATCHED SWITCH CHARACTERISTICS: \\ & R_{ON} = 5\Omega \ (Typ.) \ FOR \ V_{DD} V_{EE} = 15V \\ \hline \end{tabular}$
- WIDE RANGE OF DIGITAL AND ANALOG SIGNAL LEVELS: DIGITAL 3 to 20, ANALOG TO 20V p.p.
- QUIESCENT CURRENT SPECIFIED UP TO 20V
- 5V. 10V AND 15V PARAMETRIC RATINGS
- INPUT LEAKAGE CURRENT I<sub>I</sub> = 100nA (MAX) AT V<sub>DD</sub> = 18V T<sub>A</sub> = 25°C
- 100% TESTED FOR QUIESCENT CURRENT
- MEETS ALL REQUIREMENTS OF JEDEC JESD13B " STANDARD SPECIFICATIONS FOR DESCRIPTION OF B SERIES CMOS DEVICES"



#### **ORDER CODES**

PACKAGE	TUBE	T&R
DIP	HCF4051BEY	
SOP	HCF4051BM1	HCF4051M013TR

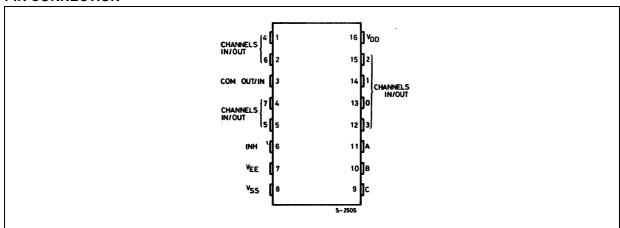
#### **DESCRIPTION**

The HCF4051B is a monolithic integrated circuit fabricated in Metal Oxide Semiconductor technology available in DIP and SOP packages.

The HCF4051B analog multiplexer/demultiplexer is a digitally controlled analog switch having low ON impedance and very low OFF leakage current. This multiplexer circuit dissipate extremely low quiescent power over the full  $V_{DD}$  -  $V_{SS}$  and  $V_{DD}$  -  $V_{EE}$  supply voltage range, independent of the logic state of the control signals.

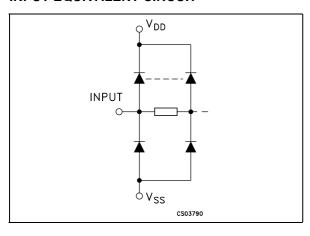
When a logic "1" is present at the inhibit input terminal all channel are off. This device is a single 8-channel multiplexer having three binary control inputs, A, B, and C, and an inhibit input. The three binary signals select 1 of 8 channels to be turned on, and connect one of the 8 inputs to the output.

#### **PIN CONNECTION**



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## **INPUT EQUIVALENT CIRCUIT**



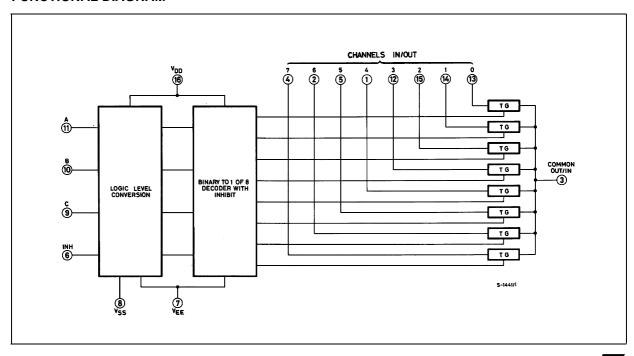
## **PIN DESCRIPTION**

PIN No	SYMBOL	NAME AND FUNCTION
11, 10, 9	A, B, C	Binary Control Inputs
6	INH	Inhibit Inputs
13, 14, 15, 12, 1, 5, 2, 4	0 to 7 CHANNEL IN/OUT	Indipendent inputs/out- puts
3	COM OUT/ IN	Common Output/Input
7	V <sub>EE</sub>	Supply Voltage
8	$V_{SS}$	Negative Supply Voltage
16	$V_{DD}$	Positive Supply Voltage

## **TRUTH TABLE**

	INPUT STATES			"ON" CHANNEL (S)			
INHIBIT	С	В	Α	ON CHANNEL (S)			
0	0	0	0	0			
0	0	0	1	1			
0	0	1	0	2			
0	0	1	1	3			
0	1	0	0	4			
0	1	0	1	5			
0	1	1	0	6			
0	1	1	1	7			
1	X	Х	X	NONE			

# **FUNCTIONAL DIAGRAM**



## **ABSOLUTE MAXIMUM RATINGS**

Symbol	Parameter	Value	Unit
$V_{DD}$	Supply Voltage	-0.5 to +22	V
VI	DC Input Voltage	-0.5 to V <sub>DD</sub> + 0.5	V
l <sub>l</sub>	DC Input Current	± 10	mA
P <sub>D</sub>	Power Dissipation per Package	500 (*)	mW
	Power Dissipation per Output Transistor	100	mW
T <sub>op</sub>	Operating Temperature	-55 to +125	°C
T <sub>stg</sub>	Storage Temperature	-65 to +150	°C

Absolute Maximum Ratings are those values beyond which damage to the device may occur. Functional operation under these conditions is not implied.

All voltage values are referred to V<sub>SS</sub> pin voltage.

(\*) 500mW at 65 °C; derate to 300mW by 10mW/°C from 65°C to 85°C

# **RECOMMENDED OPERATING CONDITIONS**

Symbol	Parameter	Value	Unit
V <sub>DD</sub>	Supply Voltage	3 to 20	V
V <sub>I</sub>	Input Voltage	0 to V <sub>DD</sub>	V
T <sub>op</sub>	Operating Temperature	-55 to 125	°C

# **DC SPECIFICATIONS**

		Test Condition				Value							
Symbol	Parameter	V <sub>IS</sub>	V <sub>EE</sub>	V <sub>SS</sub>	V <sub>DD</sub>	Т	T <sub>A</sub> = 25°C		-40 to 85°C		-55 to 125°C		Unit
		(V)	(V)	(V)	(V)	Min.	Тур.	Max.	Min.	Max.	Min.	Max.	
ΙL	Quiescent Device				5		0.04	5		150		150	
	Current (all				10		0.04	10		300		300	μA
	switches ON or all switches OFF)				15		0.04	20		600		600	μΑ
	ownorios or r j				20		0.08	100		3000		3000	
SWITCH													
R <sub>ON</sub>	Resistance	0 <u>&lt;</u> V <sub>1</sub> <u>&lt;</u>			5		470	1050		1200		1200	
		V <sub>DD</sub>	0	0	10		180	400		520		520	Ω
		. 00			15		125	280		360		360	
$\Delta_{ON}$	Resistance $\Delta_{RON}$	0 <u>&lt;</u> V <sub>1</sub> ≤			5		10						
	(between any 2 of	V <sub>DD</sub>	0	0	10		10						Ω
	4 switches)	. 00			15		5						
OFF*	Channel Leakage Current (All Channel OFF) (COMMON O/I)		0	0	18		±0.1	100		1000		1000	nA
OFF*	Channel Leakage Current (Any Channel OFF)		0	0	18		±0.1	100		1000		1000	nA
C <sub>I</sub>	Input Capacitance						5						
Co	Output Capacitance		-5	-5	5		30						pF
C <sub>IO</sub>	Feedthrough	1					0.2						
CONTRO	DL (Address or Inhi	bit)		l	l	l	l	l	l	l	l		
V <sub>IL</sub>	Input Low Voltage		V <sub>EE</sub> =	= Voo	5			1.5		1.5		1.5	
				1KΩ	10			3		3		3	V
		= VDD	to \		15			4		4		4	
V <sub>IH</sub>	Input High Voltage	thru 1KΩ		2μΑ	5	3.5			3.5		3.5		
				I OFF	10	7			7		7		V
			chan	nels)	15	11			11		11		
I <sub>IH,</sub> I <sub>IL</sub>	Input Leakage Current	VI	V <sub>I</sub> = 0/18V		18		±10 <sup>-3</sup>	±0.1		±1		±1	μΑ
C <sub>I</sub>	Input Capacitance						5	7.5					pF

<sup>\*</sup> Determined by minimum feasible leakage measurement for automating testing.

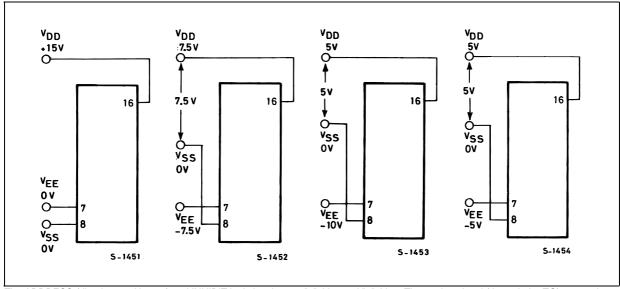
**DYNAMIC ELECTRICAL CHARACTERISTICS** ( $T_{amb} = 25^{\circ}C$ ,  $C_{L} = 50 pF$ , all input square wave rise and fall time = 20 ns )

		Value			Unit						
Parameter	V <sub>EE</sub> (V)	<b>R</b> <sub>L</sub> (ΚΩ)	f <sub>I</sub> (KHz)	<b>V</b> <sub>I</sub> (V)	V <sub>SS</sub> (V)	V <sub>DD</sub> (V)		Min.	Тур.	Max.	
Propagation Delay				$V_{DD}$		5			30	60	
Time (signal input to		200				10			15	30	ns
output)						15			11	20	
Frequency Response Channel "ON" (sine	= V <sub>SS</sub>	1		5(*)		10	V <sub>O</sub> at Common OUT/IN		20		MHz
wave input) at 20 log V <sub>O</sub> /V <sub>I</sub> = - 3dB	- * 55	'		3( )		10	V <sub>O</sub> at any channel		60		IVII IZ
Feedthrough (all channels OFF) at	= V <sub>SS</sub>	1		E/*\		10	V <sub>O</sub> at Common OUT/IN		12		MHz
$20 \log V_{O}/V_{I} = -40 dB$	- VSS	'		5(*)		10	V <sub>O</sub> at any channel		8		IVITZ
Frequency Signal Crosstalk at 20 log V <sub>O</sub> /V <sub>I</sub> = -40dB	= V <sub>SS</sub>	1		5(*)		10	Between any 2 channels		3		MHz
Circa Marra Diatantian				2(*)		5			0.3		
Sine Wave Distortion f <sub>IS</sub> = 1KHz Sine Wave	$=V_{SS}$	10	1	3(*)		10	1		0.2		%
IIS - IIII Z OIIIO VVAVO				5(*)		15	]		0.12		
CONTROL (Address	or Inhibi	t)									
Propagation Delay:	0				0	5			360	720	
Address to Signal	0				0	10			160	320	ns
OUT (Channels ON or OFF)	0				0	15			120	240	115
	<b>-</b> 5				0	5			225	450	
Propagation Delay:	0				0	5			360	720	
Inhibit to Signal OUT	0	1			0	10			160	320	ns
(Channel turning ON)	0	!			0	15			120	240	113
	-10				0	5			200	400	
Propagation Delay:	0					5			200	450	
Inhibit to Signal OUT	0	10				10			90	210	ne
(Channel turning OFF)	0	10				15			70	160	ns
	-10					5			130	300	
Address or Inhibit to Signal Crosstalk	0	10 <sup>(1)</sup>			0	10	$V_C = V_{DD} - V_{SS}$ (square wave)		65		mV peak

<sup>(1)</sup> Both ends of channel.

\* Peak to Peak voltage symmetrical about (V<sub>DD</sub> - V<sub>EE</sub> ) /2

#### **TYPICAL BIAS VOLTAGES**



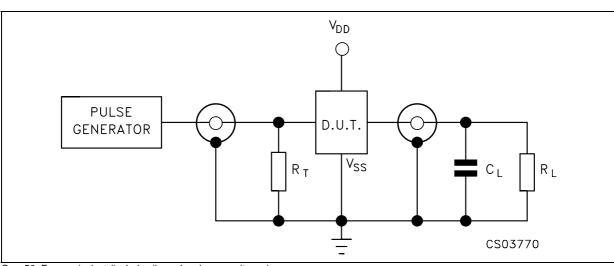
The ADDRESS (digtal-control inputs) and INHIBIT logic levels are: "0"=VSS and "1"=VDD. The analog signal (through the TG) may swing from  $V_{EE}$  to  $V_{DD}$ 

#### **SPECIAL CONSIDERATIONS**

Control of analog signals up to 20V peak to peak can be achieved by digital signal amplitudes of 4.5 to 20V (if  $V_{DD}$  -  $V_{SS}$  = 3V, a  $V_{DD}$  -  $V_{EE}$  of up to 13V can be controlled; for  $V_{DD}$  -  $V_{EE}$  level differences above 13V, a  $V_{DD}$  -  $V_{SS}$  of at least 4.5V is required. For example, if  $V_{DD}$  = +5,  $V_{SS}$  = 0, and  $V_{EE}$  = -13.5, analog signals from -13.5V to 4.5V can be controlled by digital inputs of 0 to 4.5V. In

certain applications, the external load resistor current may include both  $V_{\mbox{\scriptsize DD}}$  and signal-line components. To avoid drawing  $V_{\mbox{\scriptsize DD}}$  current when switch current flows into the transmission gate inputs, the voltage drop across the bidirectional switch must not exceed 0,8V (calculated from RON values shown in DC SPECIFICATIONS). No V<sub>DD</sub> current will flow through R<sub>L</sub> if the switch current flows into lead 3.

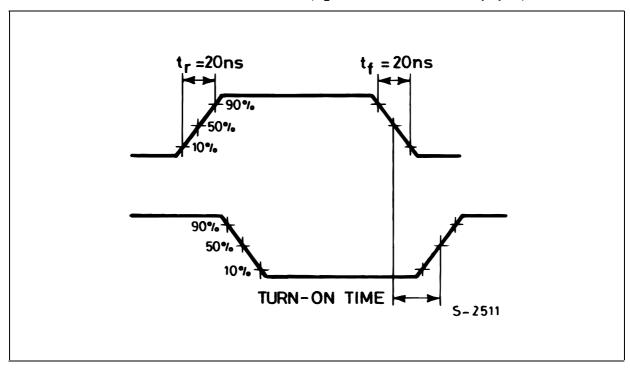
#### **TEST CIRCUIT**



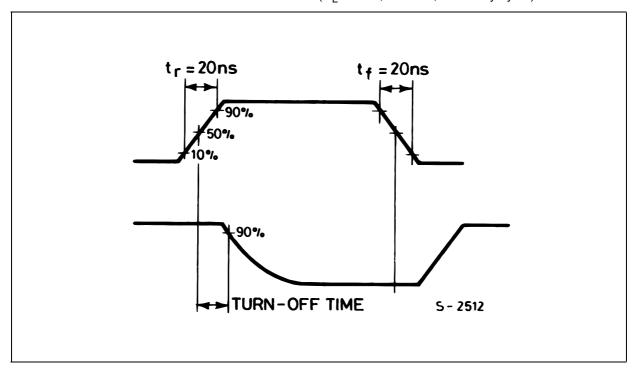
 $C_L = 50pF$  or equivalent (includes jig and probe capacitance)

 $R_L^L = 200K\Omega$   $R_T = Z_{OUT}$  of pulse generator (typically 50 $\Omega$ )

**WAVEFORM 1 : CHANNEL BEING TURNED ON** ( $R_L = 1 K\Omega$ , f=1MHz; 50% duty cycle)

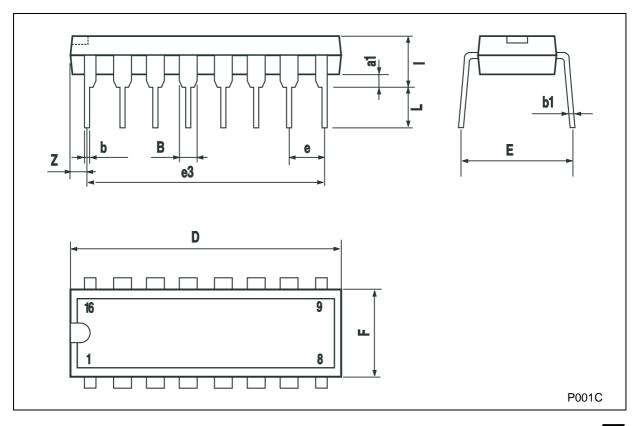


**WAVEFORM 2 : CHANNEL BEING TURNED OFF** ( $R_L$  = 1K $\Omega$ , f=1MHz; 50% duty cycle)



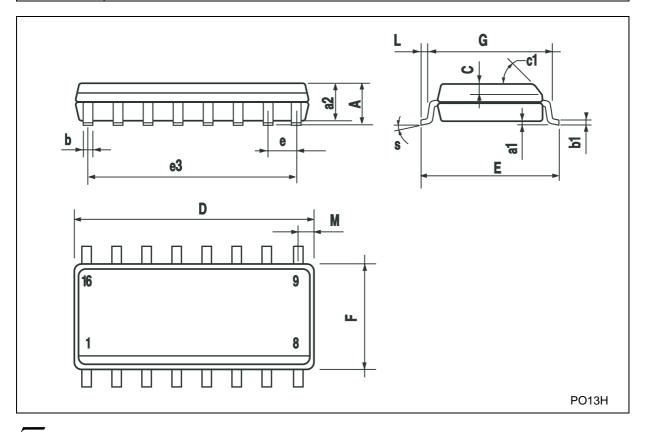
# Plastic DIP-16 (0.25) MECHANICAL DATA

DIM		mm.		inch				
DIM.	MIN.	TYP	MAX.	MIN.	TYP.	MAX.		
a1	0.51			0.020				
В	0.77		1.65	0.030		0.065		
b		0.5			0.020			
b1		0.25			0.010			
D			20			0.787		
Е		8.5			0.335			
е		2.54			0.100			
e3		17.78			0.700			
F			7.1			0.280		
I			5.1			0.201		
L		3.3			0.130			
Z			1.27			0.050		



# **SO-16 MECHANICAL DATA**

DIM		mm.		inch				
DIM.	MIN.	TYP	MAX.	MIN.	TYP.	MAX.		
Α			1.75			0.068		
a1	0.1		0.2	0.003		0.007		
a2			1.65			0.064		
b	0.35		0.46	0.013		0.018		
b1	0.19		0.25	0.007		0.010		
С		0.5			0.019			
c1			45°	(typ.)		•		
D	9.8		10	0.385		0.393		
Е	5.8		6.2	0.228		0.244		
е		1.27			0.050			
e3		8.89			0.350			
F	3.8		4.0	0.149		0.157		
G	4.6		5.3	0.181		0.208		
L	0.5		1.27	0.019		0.050		
M			0.62			0.024		
S			8° (ı	max.)				



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